

## ULTRA FAST RECOVERY RECTIFIER DIODES



Glass-passivated, high-efficiency epitaxial rectifier diodes in DO-4 metal envelopes, featuring low forward voltage drop, ultra fast reverse recovery times, very low stored charge and soft recovery characteristic. They are intended for use in switched-mode power supplies and high-frequency circuits in general, where low conduction and switching losses are essential. The series consists of normal polarity (cathode to stud) types.

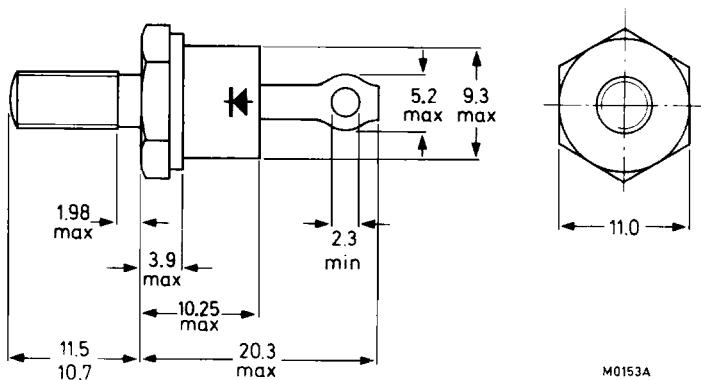
## QUICK REFERENCE DATA

		BYW31-50					
		max.	50	100	150	200	V
Repetitive peak reverse voltage	V <sub>RRM</sub>	max.					A
Average forward current	I <sub>F(AV)</sub>	max.		28			
Forward voltage	V <sub>F</sub>	<		0.8			V
Reverse recovery time	t <sub>rr</sub>	<		40			ns

## MECHANICAL DATA

Dimensions in mm

Fig.1 DO-4; with metric M5 stud ( $\phi 5$  mm); e.g. BYW31-50.  
with 10-32 UNF stud ( $\phi 4.83$  mm); e.g. BYW31-50U.



M0153A

Net mass: 7 g

Diameter of clearance hole: max. 5.2 mm

Accessories supplied on request:  
see ACCESSORIES section.

Supplied with device: 1 nut, 1 lock washer

Torque on nut: min. 0.9 Nm (9 kg cm)  
max. 1.7 Nm (17 kg cm)

Nut dimensions across the flats;  
M5: 8.0 mm; 10-32 UNF: 9.5 mm



Products approved to CECC 50 009-002, available on request.

**RATINGS**

Limiting values in accordance with the Absolute Maximum System (IEC 134).

<b>Voltages</b>		BYW31-50	100	150	200	
Repetitive peak reverse voltage	V <sub>RRM</sub>	max. 50	100	150	200	V
Crest working reverse voltage	V <sub>RWM</sub>	max. 50	100	150	200	V
Continuous reverse voltage*	V <sub>R</sub>	max. 50	100	150	200	V
<hr/>						
<b>Currents</b>						
Average forward current; switching losses negligible up to 500 kHz square wave; $\delta = 0.5$ ; up to T <sub>mb</sub> = 122 °C up to T <sub>mb</sub> = 125 °C	I <sub>F(AV)</sub>	max.	28	26	A	
sinsusoidal; up to T <sub>mb</sub> = 127 °C	I <sub>F(AV)</sub>	max.	25		A	
R.M. S. forward current	I <sub>F(RMS)</sub>	max.	40		A	
Repetitive peak forward current t <sub>p</sub> = 20 µs; $\delta = 0.02$	I <sub>FRM</sub>	max.	550		A	
Non-repetitive peak forward current half sine-wave; T <sub>j</sub> = 150 °C prior to surge; with reapplyed V <sub>RWMmax</sub> ;						
t = 10 ms	I <sub>FSM</sub>	max.	320		A	
t = 8.3 ms	I <sub>FSM</sub>	max.	380		A	
I <sup>2</sup> t for fusing (t = 10 ms)	I <sup>2</sup> t	max.	500		A <sup>2</sup> s	
<hr/>						
<b>Temperatures</b>						
Storage temperature	T <sub>stg</sub>		-55 to +150		°C	
Junction temperature	T <sub>j</sub>	max.	150		°C	
<hr/>						
<b>THERMAL RESISTANCE</b>						
From junction to mounting base	R <sub>th j-mb</sub>	=	1.0		K/W	
From mounting base to heatsink						
a. with heatsink compound	R <sub>th mb-h</sub>	=	0.3		K/W	
b. without heatsink compound	R <sub>th mb-h</sub>	=	0.5		K/W	
Transient thermal impedance: t = 1 ms	Z <sub>th j-mb</sub>	=	0.2		K/W	

**MOUNTING INSTRUCTIONS**

The top connector should be neither bent nor twisted; it should be soldered into the circuit so that there is no strain on it.

During soldering the heat conduction to the junction should be kept to a minimum.

\*To ensure thermal stability: R<sub>th j-a</sub> ≤ 4.9 K/W (continuous reverse voltage).

## CHARACTERISTICS

## Forward voltage

$I_F = 30 \text{ A}; T_j = 150^\circ\text{C}$   
 $I_F = 100 \text{ A}; T_j = 25^\circ\text{C}$

$V_F$	<	0.8	$V^*$
$V_F$	<	1.3	$V^*$

## Reverse current

$V_R = V_{RWM} \text{ max}; T_j = 100^\circ\text{C}$   
 $T_j = 25^\circ\text{C}$

$I_R$	<	1.5	$\text{mA}$
$I_R$	<	100	$\mu\text{A}$

## Reverse recovery when switched from

$I_F = 1 \text{ A}$  to  $V_R \geq 30 \text{ V}$  with  $-dI_F/dt = 100 \text{ A}/\mu\text{s}$ ;  
 $T_j = 25^\circ\text{C}$ ; recovery time

$t_{rr}$	<	40	$\text{ns}$
----------	---	----	-------------

$I_F = 2 \text{ A}$  to  $V_R \geq 30 \text{ V}$  with  $-dI_F/dt = 20 \text{ A}/\mu\text{s}$ ;  
 $T_j = 25^\circ\text{C}$ ; recovered charge

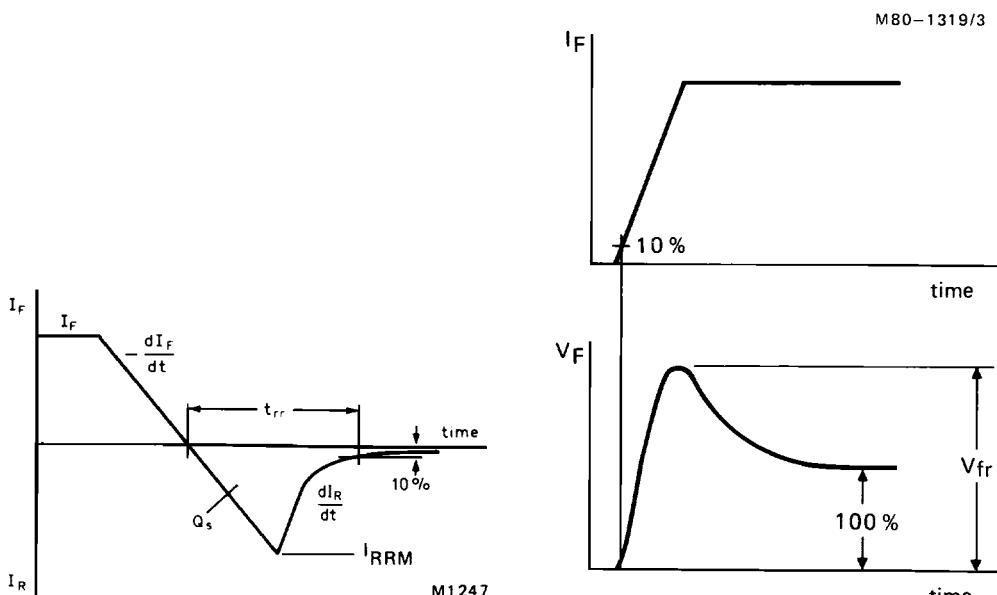
$Q_s$	<	20	$\text{nC}$
-------	---	----	-------------

$I_F = 10 \text{ A}$  to  $V_R \geq 30 \text{ V}$  with  $-dI_F/dt = 50 \text{ A}/\mu\text{s}$ ;  
 $T_j = 100^\circ\text{C}$ ; peak recovery current

$I_{RRM}$	<	4	$\text{A}$
-----------	---	---	------------

Forward recovery when switched to  $I_F = 10 \text{ A}$   
with  $dI_F/dt = 10 \text{ A}/\mu\text{s}$ ;  $T_j = 25^\circ\text{C}$ 

$V_{fr}$	typ.	1	$\text{V}$
----------	------	---	------------

Fig.2 Definition of  $t_{rr}$ ,  $Q_s$  and  $I_{RRM}$ .Fig.3 Definition of  $V_{fr}$ .

\* Measured under pulse conditions to avoid excessive dissipation.

## SQUARE-WAVE OPERATION

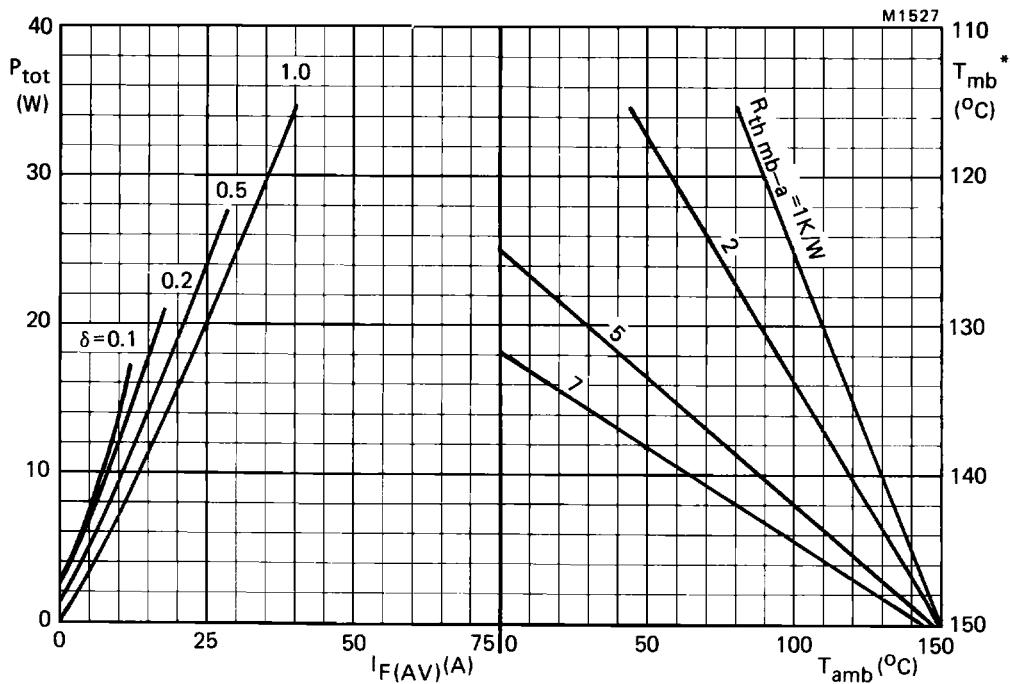
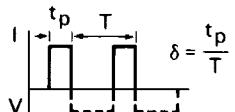


Fig.4 The right-hand part shows the interrelationship between the power (derived from the left-hand part) and the maximum permissible temperatures. Power includes reverse current losses and switching losses up to  $f = 500 \text{ kHz}$ .



$$I_F(\text{AV}) = I_F(\text{RMS}) \times \sqrt{\delta}$$

\*  $T_{mb}$  scale is for comparison purposes and is correct only for  $R_{th\text{ mb-a}} < 3.6 \text{ K/W}$ .

## SINUSOIDAL OPERATION

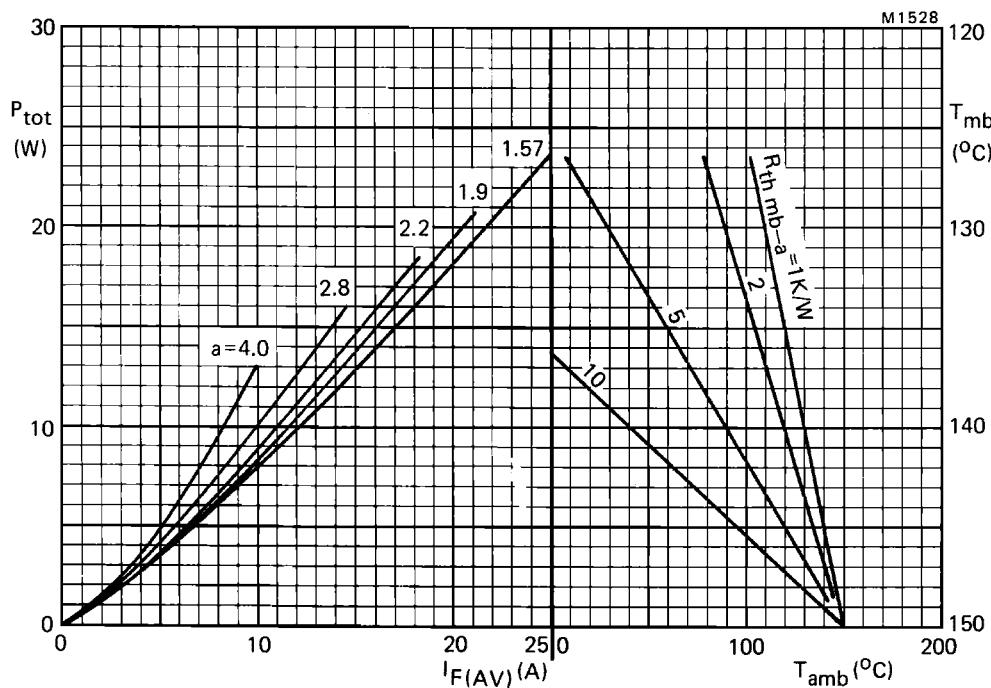


Fig.5 The right-hand part shows the interrelationship between the power (derived from the left-hand part) and the maximum permissible temperatures. Power includes reverse current losses and switching losses up to  $f = 500$  kHz.  
 $a$  = form factor =  $I_F(\text{RMS})/I_F(\text{AV})$ .

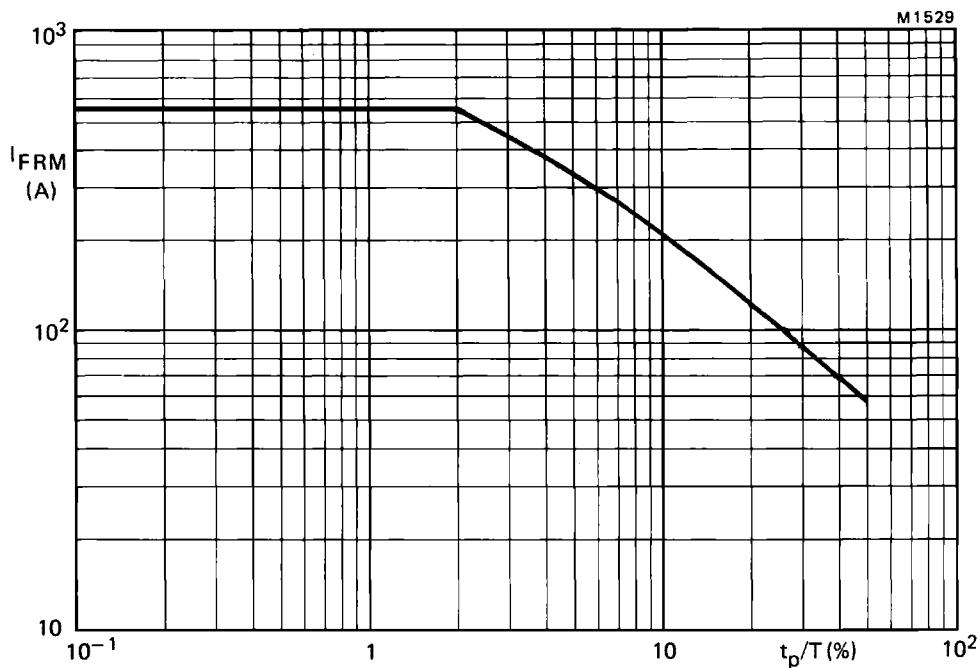
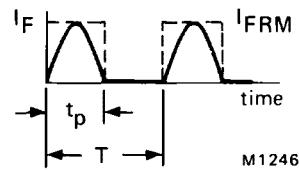
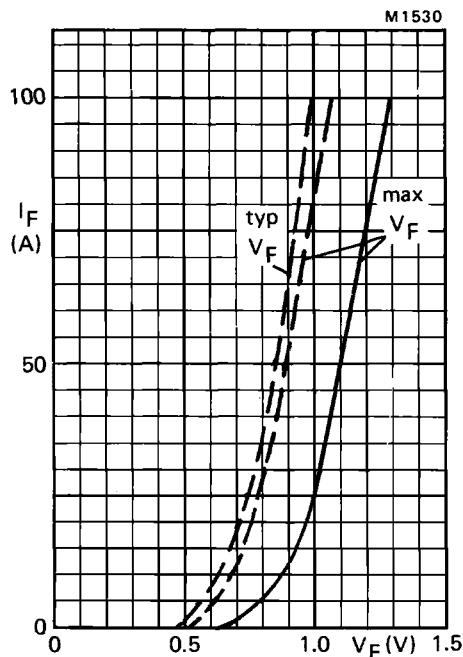
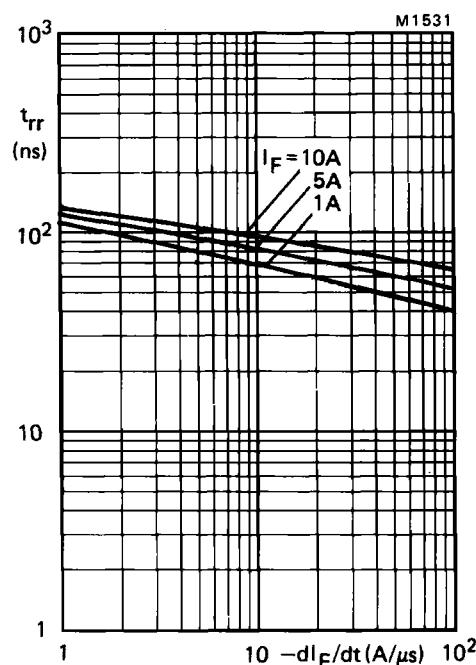
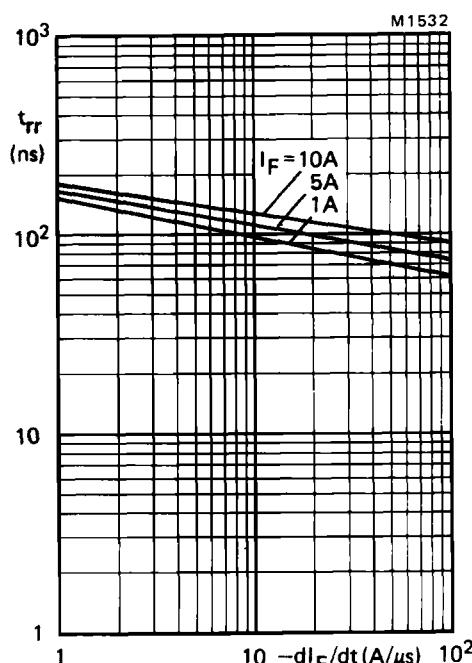
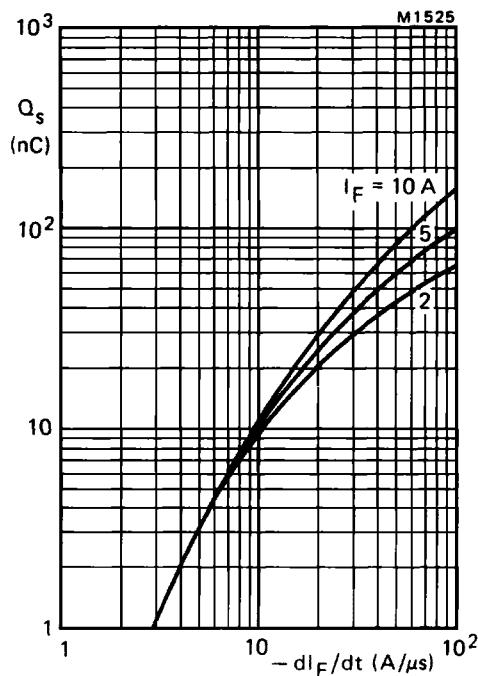


Fig.6 Maximum permissible repetitive peak forward current for square or sinusoidal currents;  
 $1 \mu\text{s} < t_p < 1 \text{ ms}$ .



Definition of  $I_{FRM}$   
and  $t_p/T$ .

Fig.7 ———  $T_j = 25^\circ\text{C}$ ; - - -  $T_j = 150^\circ\text{C}$ .

Fig.8 Maximum  $t_{rr}$  at  $T_j = 25^\circ C$ .Fig.9 Maximum  $t_{rr}$  at  $T_j = 100^\circ C$ .Fig.10 Maximum  $Q_s$  at  $T_j = 25^\circ C$ .

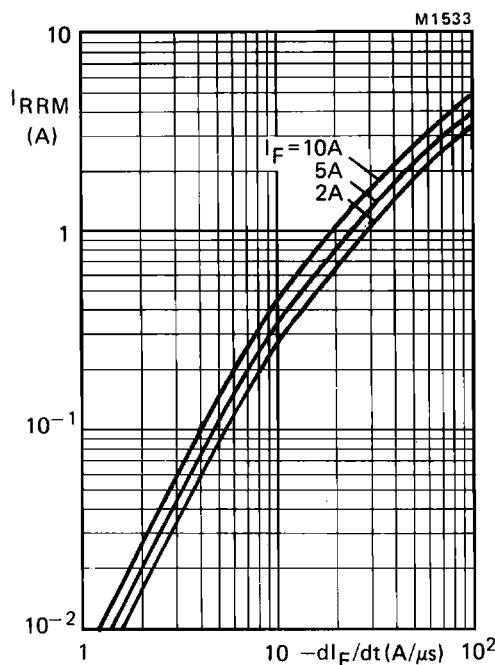


Fig.11 Maximum  $I_{RRM}$  at  $T_j = 25^\circ C$ .

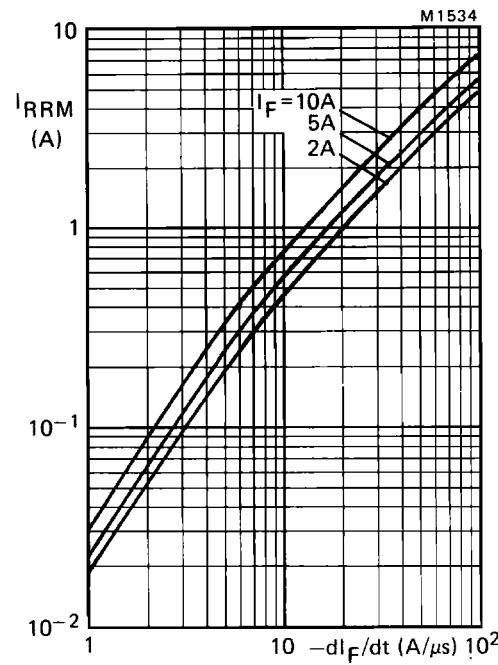


Fig.12 Maximum  $I_{RRM}$  at  $T_j = 100^\circ C$ .

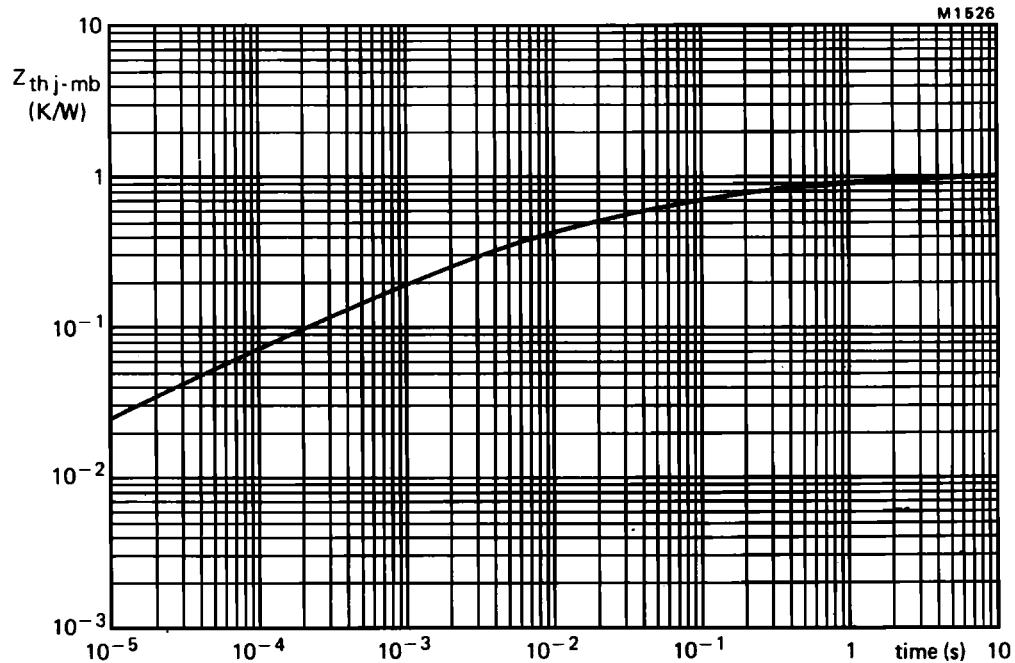


Fig.13 Transient thermal impedance.